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60-V N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD18533Q5A

FEATURES

- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- Logic Level
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

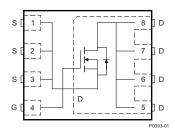
APPLICATIONS

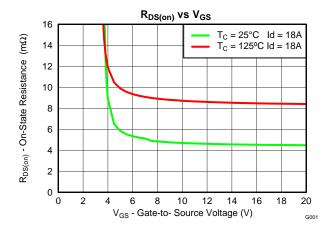
- DC-DC Conversion
- Secondary Side Synchronous Rectifier
- Motor Control

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Figure 1. Top View





PRODUCT SUMMARY

	/alues at 25°C therwise stated	TYPICAL VA	UNIT	
V _{DS}	Drain to Source Voltage	60	V	
Q_g	Gate Charge Total (10V)	29	nC	
Q_{gd}	Gate Charge Gate to Drain	5.4		nC
D	Drain to Source On Resistance	$V_{GS} = 4.5V$	6.5	mΩ
R _{DS(on)}	Diam to Source On Resistance	urce On Resistance $V_{GS} = 10V$ 4.7		mΩ
$V_{GS(th)}$	Threshold Voltage	1.9		V

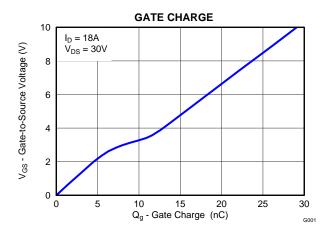
ORDERING INFORMATION

Device	Package	Media	Qty	Ship	
CSD18533Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel	

ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	60	V
V_{GS}	Gate to Source Voltage	±20	٧
	Continuous Drain Current (Package limited), T _C = 25°C	100	
I _D	Continuous Drain Current (Silicon limited), $T_C = 25$ °C	77	Α
	Continuous Drain Current, T _A = 25°C ⁽¹⁾	17	
I_{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	107	Α
P _D	Power Dissipation ⁽¹⁾	3.2	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 53A$, $L = 0.1mH$, $R_G = 25\Omega$	140	mJ

- (1) Typical $R_{\theta JA} = 40^{\circ} C/W$ on a 1-inch², 2-oz. Cu pad on a 0.06-inch thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%



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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

STRUMENTS



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Ch	naracteristics					
BV_{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	60			V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 48V$			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = 20V$			100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_{D} = 250 \mu A$	1.5	1.9	2.3	V
_	Dunin to Course On Bonistano	V _{GS} = 4.5V, I _D = 18A		6.5	8.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V, I _D = 18A		4.7	5.9	mΩ
9 _{fs}	Transconductance	V _{DS} = 30V, I _D = 18A		122		S
Dynamic	: Characteristics					
C _{iss}	Input Capacitance			2200	2750	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 30V, f = 1MHz$		292	365	pF
C _{rss}	Reverse Transfer Capacitance			7	9	pF
R_G	Series Gate Resistance			1.3	2.6	Ω
Qg	Gate Charge Total (4.5V)			14	18	nC
Qg	Gate Charge Total (10V)			29	36	nc
Q_{gd}	Gate Charge Gate to Drain	$V_{DS} = 30V, I_{D} = 18A$		5.4		nC
Q_{gs}	Gate Charge Gate to Source			6.6		nC
Q _{g(th)}	Gate Charge at Vth			4.7		nC
Q _{oss}	Output Charge	$V_{DS} = 30V, V_{GS} = 0V$		31		nC
t _{d(on)}	Turn On Delay Time			5.2		ns
t _r	Rise Time	V 20V V 40V L 48A B 00		5.5		ns
t _{d(off)}	Turn Off Delay Time	$V_{DS} = 30V, V_{GS} = 10V, I_{DS} = 18A, R_G = 0\Omega$		15		ns
t _f	Fall Time			2.0		ns
Diode Cl	naracteristics					
V _{SD}	Diode Forward Voltage	I _{SD} = 18A, V _{GS} = 0V		8.0	1	V
Q_{rr}	Reverse Recovery Charge	\/ - 20\/ - 19\ di/dt - 200\/\/\		68		nC
t _{rr}	Reverse Recovery Time	V_{DS} = 30V, I_F = 18A, di/dt = 300A/ μ s		40		ns

THERMAL CHARACTERISTICS

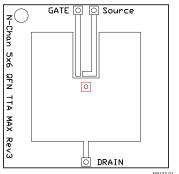
(T_A = 25°C unless otherwise stated)

	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			2.3	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (1)(2)			50	°C/W

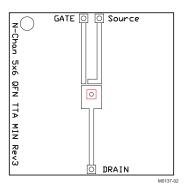
 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

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Max $R_{\theta JA} = 50^{\circ}C/W$ when mounted on 1 inch2 (6.45 cm2) of 2oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 121$ °C/W when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

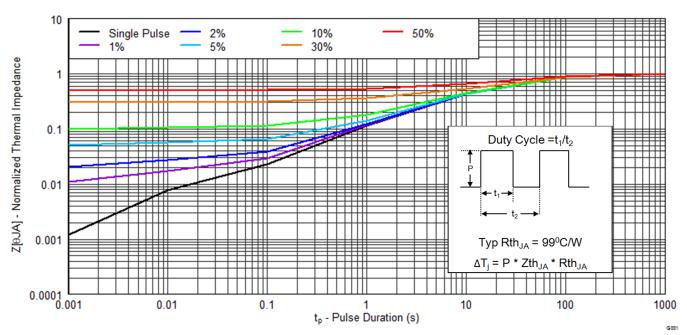


Figure 2. Transient Thermal Impedance

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TEXAS INSTRUMENTS

TYPICAL MOSFET CHARACTERISTICS (continued)

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

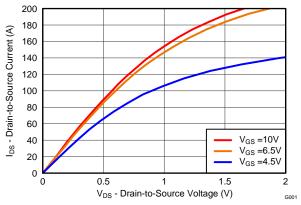


Figure 3. Saturation Characteristics

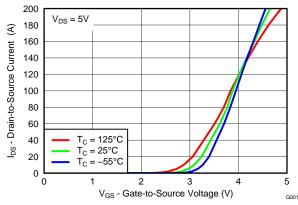


Figure 4. Transfer Characteristics

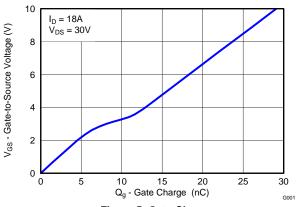


Figure 5. Gate Charge

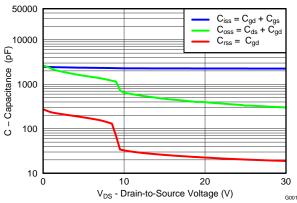


Figure 6. Capacitance

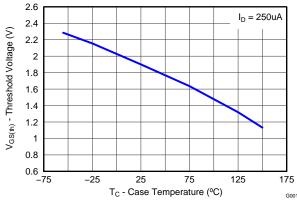


Figure 7. Threshold Voltage vs. Temperature

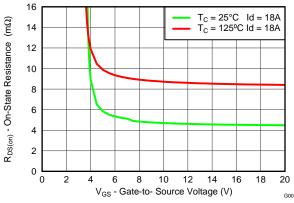


Figure 8. On-State Resistance vs. Gate-to-Source Voltage

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

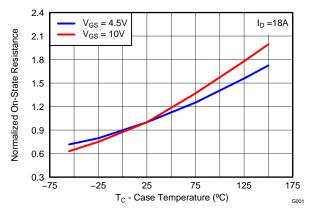


Figure 9. Normalized On-State Resistance vs. Temperature

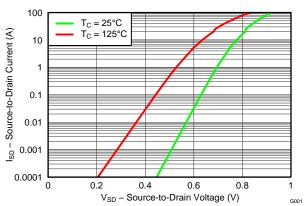


Figure 10. Typical Diode Forward Voltage

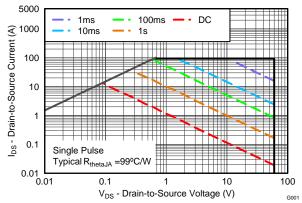


Figure 11. Maximum Safe Operating Area

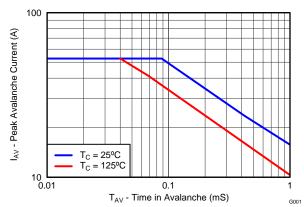


Figure 12. Single Pulse Unclamped Inductive Switching

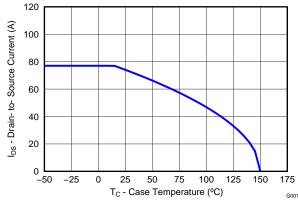


Figure 13. Maximum Drain Current vs. Temperature

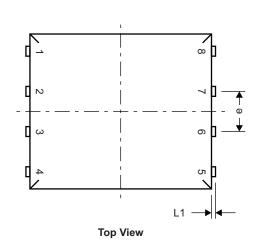
Product Folder Links: CSD18533Q5A

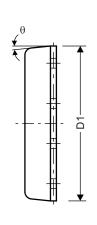
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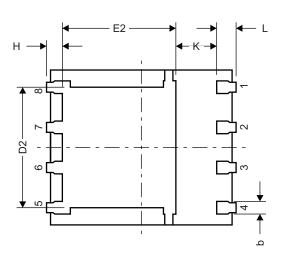
MECHANICAL DATA

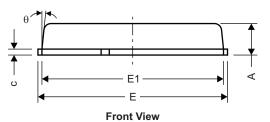
Q5A Package Dimensions





Side View





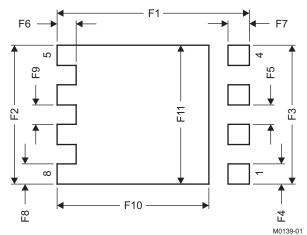
Bottom View

M0135-01

DIM	MILLIMETERS							
DIM	MIN	NOM	MAX					
Α	0.90	1.00	1.10					
b	0.33	0.41	0.51					
С	0.20	0.25	0.34					
D1	4.80	4.90	5.00					
D2	3.61	3.81	4.02					
Е	5.90	6.00	6.10					
E1	5.70	5.75	5.80					
E2	3.38	3.58	3.78					
е	1.17	1.27	1.37					
Н	0.41	0.56	0.71					
K	1.10							
L	0.51	0.61	0.71					
L1	0.06	0.13	0.20					
θ	0°		12°					

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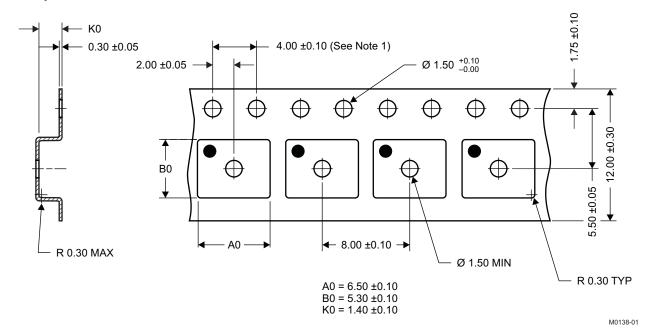
Figure 14. Recommended PCB Pattern



DIM	MILLIN	IETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65 0.62	0.7	0.026	0.028
F5		0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

Product Folder Links: CSD18533Q5A



PACKAGE OPTION ADDENDUM

28-Sep-2012

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Typ	e Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
CSD18533Q5A	ACTIVE	SON	DQJ	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18533Q5A	SON	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

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*All dimensions are nominal

	Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	CSD18533Q5A	SON	DQJ	8	2500	340.0	340.0	38.0	

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